# NSN 5961-01-020-1669

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Overall	Laiabte	
Overan	Height:	

Between 0.320 inches and 0.468 inches

**Internal Configuration:** 

Junction contact

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

Between 0.423 inches and 0.438 inches

**Semiconductor Material:** 

Silicon

## Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 125.0 collector to emitter voltage/static/base open and 20.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 25.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector preset

## **Special Features:**

Junction pattern arrangement: npn

## **Test Data Document:**

82577-928482 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

4 tab, solder lug

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0